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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	8051
Core Size	8-Bit
Speed	50MHz
Connectivity	EBI/EMI, I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	CapSense, DMA, LCD, POR, PWM, WDT
Number of I/O	38
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	512 x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	A/D 16x12b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	68-VFQFN Exposed Pad
Supplier Device Package	68-QFN (8x8)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/infineon-technologies/cy8c3444lti-110t">https://www.e-xfl.com/product-detail/infineon-technologies/cy8c3444lti-110t</a>

## More Information

Cypress provides a wealth of data at [www.cypress.com](http://www.cypress.com) to help you to select the right PSoC device for your design, and to help you to quickly and effectively integrate the device into your design. For a comprehensive list of resources, see the knowledge base article [KBA86521](#), [How to Design with PSoC 3](#), [PSoC 4](#), and [PSoC 5LP](#). Following is an abbreviated list for PSoC 3:

### ■ Overview: [PSoC Portfolio](#), [PSoC Roadmap](#)

### ■ Product Selectors: [PSoC 1](#), [PSoC 3](#), [PSoC 4](#), [PSoC 5LP](#) In addition, PSoC Creator includes a device selection tool.

### ■ Application notes: Cypress offers a large number of PSoC application notes and [code examples](#) covering a broad range of topics, from basic to advanced level. Recommended application notes for getting started with PSoC 3 are:

- [AN54181](#): Getting Started With PSoC 3
- [AN61290](#): Hardware Design Considerations
- [AN57821](#): Mixed Signal Circuit Board Layout
- [AN58304](#): Pin Selection for Analog Designs
- [AN81623](#): Digital Design Best Practices
- [AN73854](#): Introduction To Bootloaders

### ■ Development Kits:

- [CY8CKIT-030](#) is designed for analog performance, for developing high-precision analog, low-power, and low-voltage applications.
- [CY8CKIT-001](#) provides a common development platform for any one of the PSoC 1, PSoC 3, PSoC 4, or PSoC 5LP families of devices.
- The [MiniProg3](#) device provides an interface for flash programming and debug.

### ■ Technical Reference Manuals (TRM)

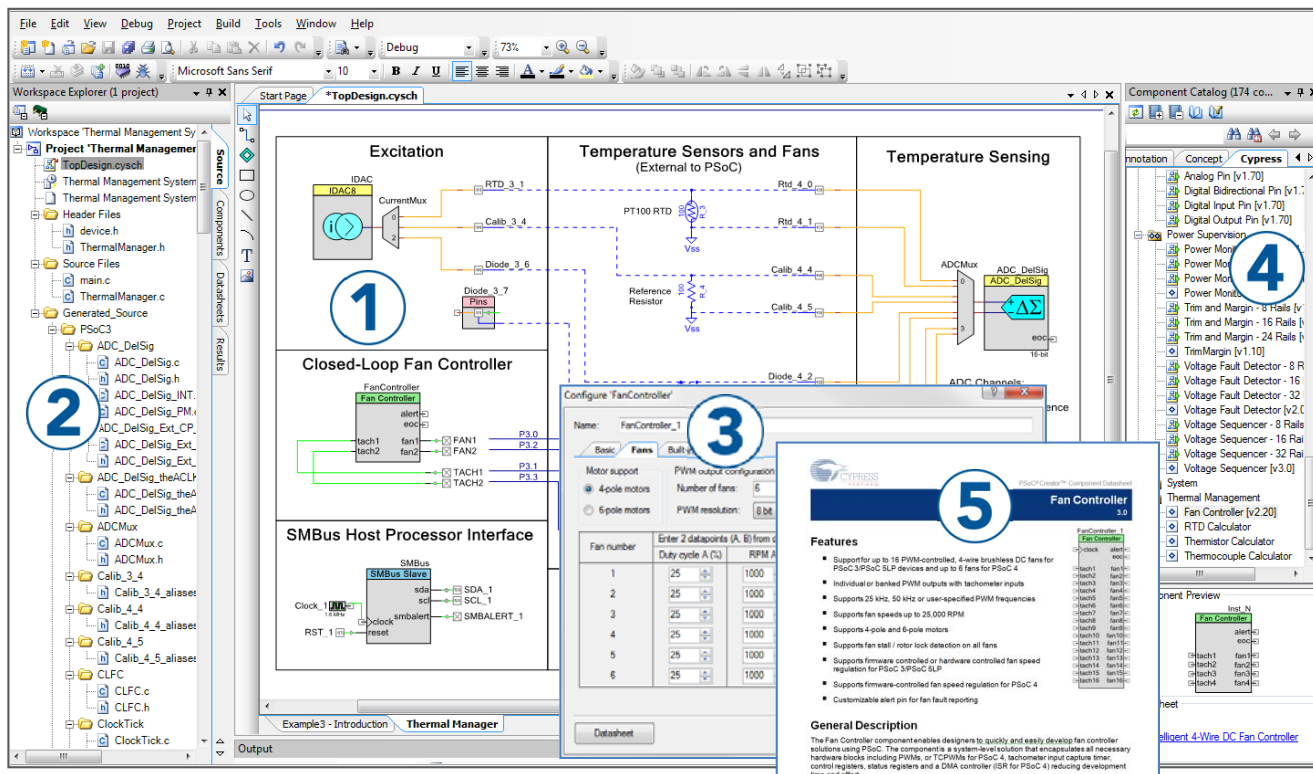
- [Architecture TRM](#)
- [Registers TRM](#)
- [Programming Specification](#)

## PSoC Creator

[PSoC Creator](#) is a free Windows-based Integrated Design Environment (IDE). It enables concurrent hardware and firmware design of PSoC 3, PSoC 4, and PSoC 5LP based systems. Create designs using classic, familiar schematic capture supported by over 100 pre-verified, production-ready PSoC Components; see the [list of component datasheets](#). With PSoC Creator, you can:

1. Drag and drop component icons to build your hardware system design in the main design workspace
2. Codesign your application firmware with the PSoC hardware, using the PSoC Creator IDE C compiler
3. Configure components using the configuration tools
4. Explore the library of 100+ components
5. Review component datasheets

**Figure 1. Multiple-Sensor Example Project in PSoC Creator**



## 4.3 Instruction Set

The 8051 instruction set is highly optimized for 8-bit handling and Boolean operations. The types of instructions supported include:

- Arithmetic instructions
- Logical instructions
- Data transfer instructions
- Boolean instructions
- Program branching instructions

### 4.3.1 Instruction Set Summary

#### 4.3.1.1 Arithmetic Instructions

Arithmetic instructions support the direct, indirect, register, immediate constant, and register-specific instructions. Arithmetic modes are used for addition, subtraction, multiplication, division, increment, and decrement operations. [Table 4-1](#) lists the different arithmetic instructions.

**Table 4-1. Arithmetic Instructions**

Mnemonic	Description	Bytes	Cycles
ADD A,Rn	Add register to accumulator	1	1
ADD A,Direct	Add direct byte to accumulator	2	2
ADD A,@Ri	Add indirect RAM to accumulator	1	2
ADD A,#data	Add immediate data to accumulator	2	2
ADDC A,Rn	Add register to accumulator with carry	1	1
ADDC A,Direct	Add direct byte to accumulator with carry	2	2
ADDC A,@Ri	Add indirect RAM to accumulator with carry	1	2
ADDC A,#data	Add immediate data to accumulator with carry	2	2
SUBB A,Rn	Subtract register from accumulator with borrow	1	1
SUBB A,Direct	Subtract direct byte from accumulator with borrow	2	2
SUBB A,@Ri	Subtract indirect RAM from accumulator with borrow	1	2
SUBB A,#data	Subtract immediate data from accumulator with borrow	2	2
INC A	Increment accumulator	1	1
INC Rn	Increment register	1	2
INC Direct	Increment direct byte	2	3
INC @Ri	Increment indirect RAM	1	3
DEC A	Decrement accumulator	1	1
DEC Rn	Decrement register	1	2
DEC Direct	Decrement direct byte	2	3
DEC @Ri	Decrement indirect RAM	1	3
INC DPTR	Increment data pointer	1	1
MUL	Multiply accumulator and B	1	2
DIV	Divide accumulator by B	1	6
DAA	Decimal adjust accumulator	1	3

## 4.3.1.3 Data Transfer Instructions

The data transfer instructions are of three types: the core RAM, xdata RAM, and the lookup tables. The core RAM transfer includes transfer between any two core RAM locations or SFRs. These instructions can use direct, indirect, register, and immediate addressing. The xdata RAM transfer includes only the transfer between the accumulator and the xdata RAM location. It can use only indirect addressing. The lookup tables involve nothing but the read of program memory using the Indexed addressing mode. [Table 4-3](#) lists the various data transfer instructions available.

## 4.3.1.4 Boolean Instructions

The 8051 core has a separate bit addressable memory location. It has 128 bits of bit-addressable RAM and a set of SFRs that are bit addressable. The instruction set includes the whole menu of bit operations such as move, set, clear, toggle, OR, and AND instructions and the conditional jump instructions. [Table 4-4](#) on page 16 lists the available Boolean instructions.

**Table 4-3. Data Transfer Instructions**

Mnemonic	Description	Bytes	Cycles
MOV A,Rn	Move register to accumulator	1	1
MOV A,Direct	Move direct byte to accumulator	2	2
MOV A,@Ri	Move indirect RAM to accumulator	1	2
MOV A,#data	Move immediate data to accumulator	2	2
MOV Rn,A	Move accumulator to register	1	1
MOV Rn,Direct	Move direct byte to register	2	3
MOV Rn, #data	Move immediate data to register	2	2
MOV Direct, A	Move accumulator to direct byte	2	2
MOV Direct, Rn	Move register to direct byte	2	2
MOV Direct, Direct	Move direct byte to direct byte	3	3
MOV Direct, @Ri	Move indirect RAM to direct byte	2	3
MOV Direct, #data	Move immediate data to direct byte	3	3
MOV @Ri, A	Move accumulator to indirect RAM	1	2
MOV @Ri, Direct	Move direct byte to indirect RAM	2	3
MOV @Ri, #data	Move immediate data to indirect RAM	2	2
MOV DPTR, #data16	Load data pointer with 16-bit constant	3	3
MOVC A, @A+DPTR	Move code byte relative to DPTR to accumulator	1	5
MOVC A, @A + PC	Move code byte relative to PC to accumulator	1	4
MOVX A,@Ri	Move external RAM (8-bit) to accumulator	1	4
MOVX A, @DPTR	Move external RAM (16-bit) to accumulator	1	3
MOVX @Ri, A	Move accumulator to external RAM (8-bit)	1	5
MOVX @DPTR, A	Move accumulator to external RAM (16-bit)	1	4
PUSH Direct	Push direct byte onto stack	2	3
POP Direct	Pop direct byte from stack	2	2
XCH A, Rn	Exchange register with accumulator	1	2
XCH A, Direct	Exchange direct byte with accumulator	2	3
XCH A, @Ri	Exchange indirect RAM with accumulator	1	3
XCHD A, @Ri	Exchange low order indirect digit RAM with accumulator	1	3

6: CPU acknowledges the interrupt request

7: ISR address is read by CPU for branching

8, 9: PEND and POST bits are cleared respectively after receiving the IRA from core

10: IRA bit is cleared after completing the current instruction and starting the instruction execution from ISR location (takes 7 cycles)

11: IRC is set to indicate the completion of ISR, Active int. status is restored with previous status

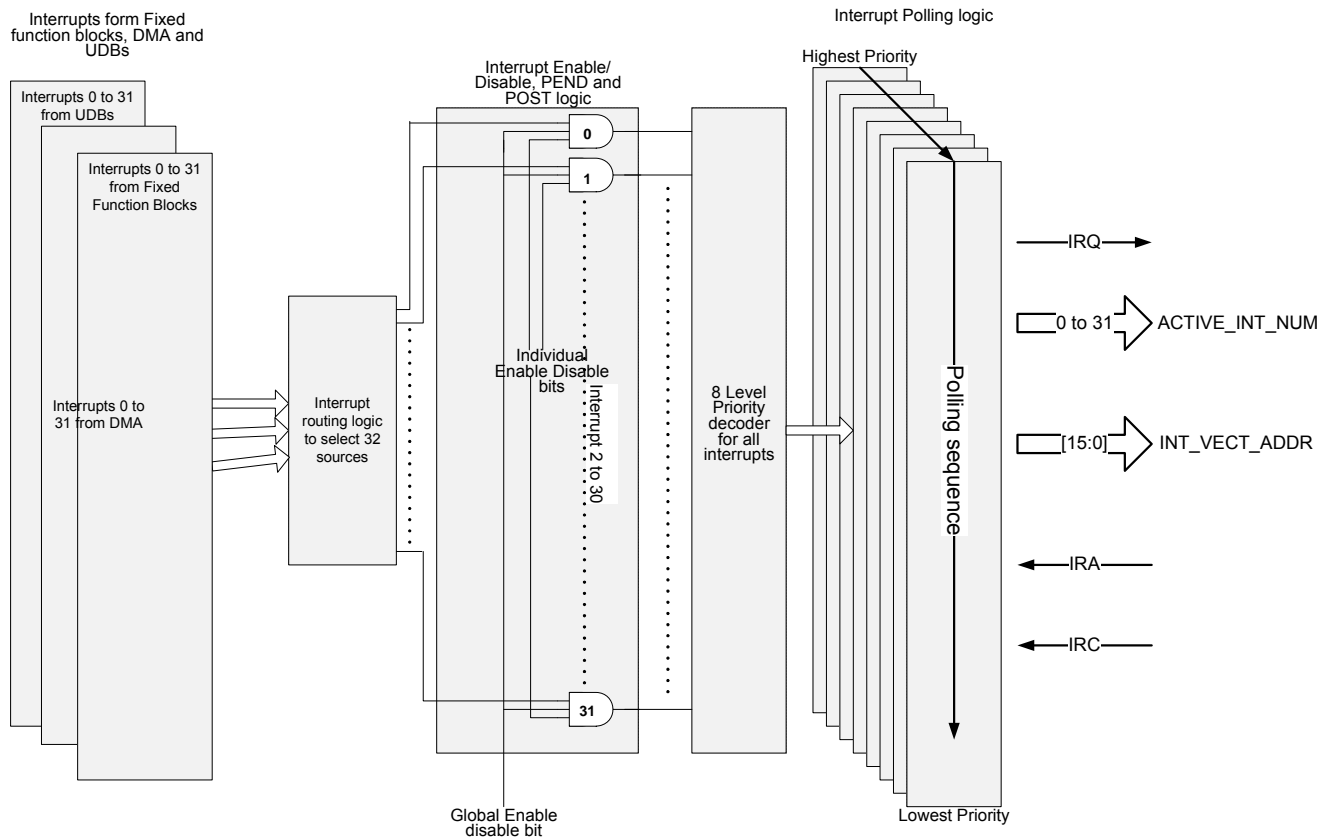
The total interrupt latency (ISR execution)

= POST + PEND + IRQ + IRA + Completing current instruction and branching

= 1+1+1+2+7 cycles

= 12 cycles

**Figure 4-3. Interrupt Structure**



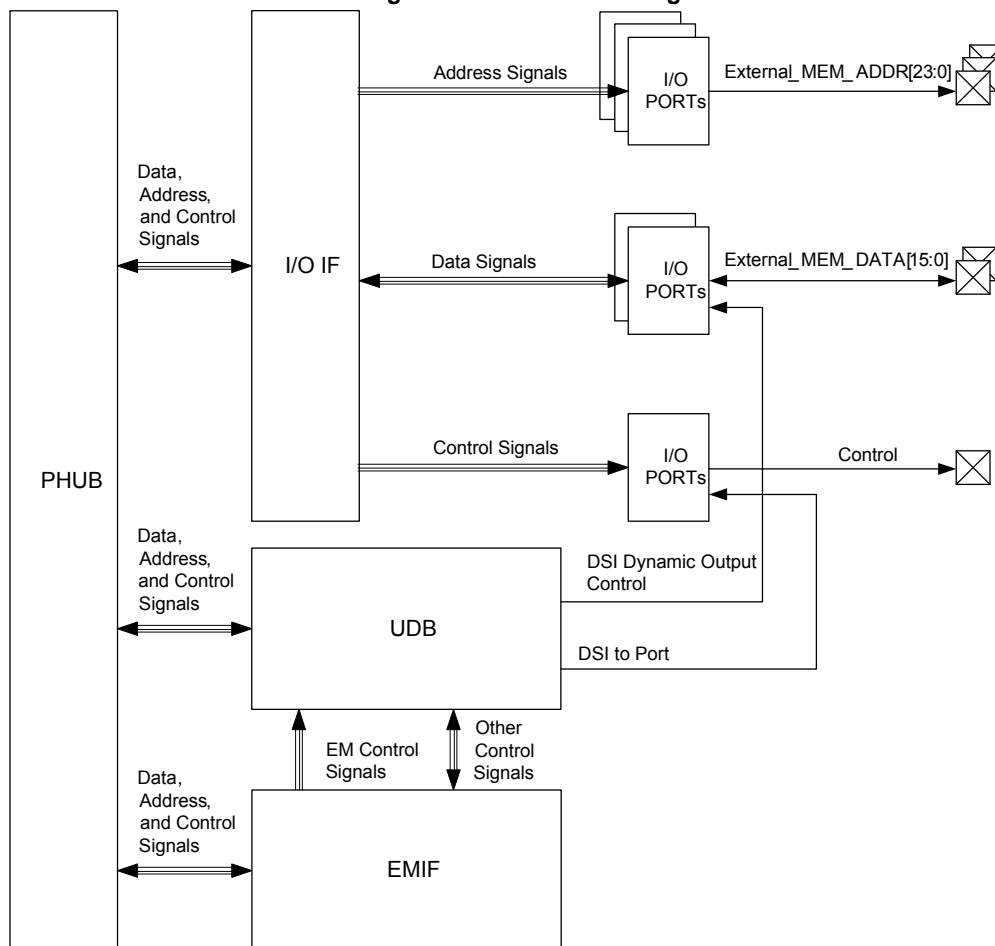
## 5.6 External Memory Interface

CY8C34 provides an External Memory Interface (EMIF) for connecting to external memory devices. The connection allows read and write accesses to external memories. The EMIF operates in conjunction with UDBs, I/O ports, and other hardware to generate external memory address and control signals. At 33 MHz, each memory access cycle takes four bus clock cycles.

Figure 5-1 is the EMIF block diagram. The EMIF supports synchronous and asynchronous memories. The CY8C34 supports only one type of external memory device at a time.

External memory can be accessed via the 8051 xdata space; up to 24 address bits can be used. See “xdata Space” section on page 26. The memory can be 8 or 16 bits wide.

**Figure 5-1. EMIF Block Diagram**



debug on chip mode. It can be used to generate periodic interrupts for timing purposes or to wake the system from a low-power mode. Firmware can reset the central timewheel. Systems that require accurate timing should use the RTC capability instead of the central timewheel.

The 100-kHz clock (CLK100K) can be used as a low power master clock. It can also generate time intervals using the fast timewheel.

The fast timewheel is a 5-bit counter, clocked by the 100-kHz clock. It features programmable settings and automatically resets when the terminal count is reached. An optional interrupt can be generated each time the terminal count is reached. This enables flexible, periodic interrupts of the CPU at a higher rate than is allowed using the central timewheel.

The 33 kHz clock (CLK33K) comes from a divide-by-3 operation on CLK100K. This output can be used as a reduced accuracy version of the 32.768-kHz ECO clock with no need for a crystal.

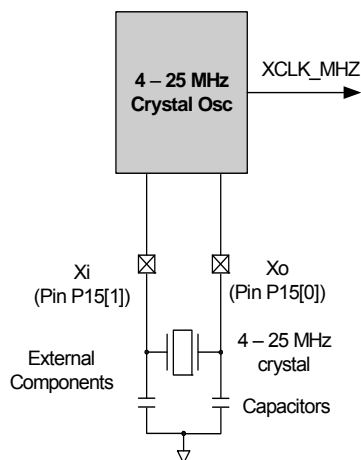
## 6.1.2 External Oscillators

Figure 6-1 shows that there are two external oscillators. They can be routed directly or divided. The direct routes may not have a 50% duty cycle. Divided clocks have a 50% duty cycle.

### 6.1.2.1 MHz External Crystal Oscillator

The MHzECO provides high frequency, high precision clocking using an external crystal (see Figure 6-2). It supports a wide variety of crystal types, in the range of 4 to 25 MHz. When used in conjunction with the PLL, it can generate other clocks up to the device's maximum frequency (see "Phase-Locked Loop" section on page 28). The GPIO pins connecting to the external crystal and capacitors are fixed. MHzECO accuracy depends on the crystal chosen.

**Figure 6-2. MHzECO Block Diagram**

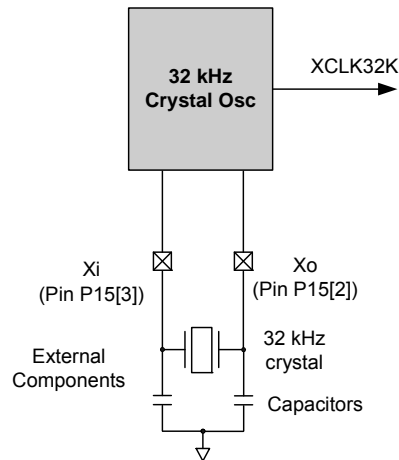


### 6.1.2.2 32.768-kHz ECO

The 32.768-kHz External Crystal Oscillator (32kHzECO) provides precision timing with minimal power consumption using an external 32.768-kHz watch crystal (see Figure 6-3). The 32kHzECO also connects directly to the sleep timer and provides the source for the RTC. The RTC uses a 1-second interrupt to implement the RTC functionality in firmware.

The oscillator works in two distinct power modes. This allows users to trade off power consumption with noise immunity from neighboring circuits. The GPIO pins connected to the external crystal and capacitors are fixed.

**Figure 6-3. 32kHzECO Block Diagram**



It is recommended that the external 32.768-kHz watch crystal have a load capacitance (CL) of 6 pF or 12.5 pF. Check the crystal manufacturer's datasheet. The two external capacitors, CL1 and CL2, are typically of the same value, and their total capacitance,  $CL1CL2 / (CL1 + CL2)$ , including pin and trace capacitance, should equal the crystal CL value. For more information, refer to application note [AN54439: PSoC 3 and PSoC 5 External Oscillators](#). See also pin capacitance specifications in the "GPIO" section on page 79.

### 6.1.2.3 Digital System Interconnect

The DSI provides routing for clocks taken from external clock oscillators connected to I/O. The oscillators can also be generated within the device in the digital system and Universal Digital Blocks.

While the primary DSI clock input provides access to all clocking resources, up to eight other DSI clocks (internally or externally generated) may be routed directly to the eight digital clock dividers. This is only possible if there are multiple precision clock sources.

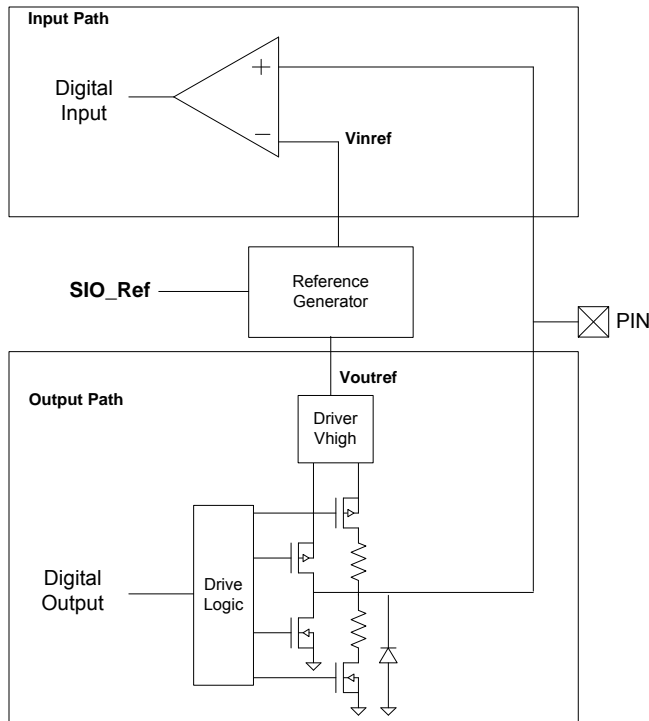
### 6.1.3 Clock Distribution

All seven clock sources are inputs to the central clock distribution system. The distribution system is designed to create multiple high precision clocks. These clocks are customized for the design's requirements and eliminate the common problems found with limited resolution prescalers attached to peripherals. The clock distribution system generates several types of clock trees.

- The master clock is used to select and supply the fastest clock in the system for general clock requirements and clock synchronization of the PSoC device.
- Bus Clock 16-bit divider uses the master clock to generate the bus clock used for data transfers. Bus clock is the source clock for the CPU clock divider.
- Eight fully programmable 16-bit clock dividers generate digital system clocks for general use in the digital system, as configured by the design's requirements. Digital system clocks



**Figure 6-13. SIO Reference for Input and Output**



## 6.4.13 SIO as Comparator

This section applies only to SIO pins. The adjustable input level feature of the SIOs as explained in the [Adjustable Input Level](#) section can be used to construct a comparator. The threshold for the comparator is provided by the SIO's reference generator. The reference generator has the option to set the analog signal routed through the analog global line as threshold for the comparator. Note that a pair of SIO pins share the same threshold.

The digital input path in [Figure 6-10](#) on page 38 illustrates this functionality. In the figure, 'Reference level' is the analog signal routed through the analog global. The hysteresis feature can also be enabled for the input buffer of the SIO, which increases noise immunity for the comparator.

## 6.4.14 Hot Swap

This section applies only to SIO pins. SIO pins support 'hot swap' capability to plug into an application without loading the signals that are connected to the SIO pins even when no power is applied to the PSoC device. This allows the unpowered PSoC to maintain a high impedance load to the external device while also preventing the PSoC from being powered through a SIO pin's protection diode.

Powering the device up or down while connected to an operational I2C bus may cause transient states on the SIO pins. The overall I2C bus design should take this into account.

## 6.4.15 Over Voltage Tolerance

All I/O pins provide an over voltage tolerance feature at any operating  $V_{DD}$ .

- There are no current limitations for the SIO pins as they present a high impedance load to the external circuit where  $V_{DDIO} \leq V_{IN} \leq 5.5$  V.
- The GPIO pins must be limited to 100  $\mu$ A using a current limiting resistor. GPIO pins clamp the pin voltage to approximately one diode above the  $V_{DDIO}$  supply where  $V_{DDIO} \leq V_{IN} \leq V_{DDA}$ .
- In case of a GPIO pin configured for analog input/output, the analog voltage on the pin must not exceed the  $V_{DDIO}$  supply voltage to which the GPIO belongs.

A common application for this feature is connection to a bus such as I<sup>2</sup>C where different devices are running from different supply voltages. In the I<sup>2</sup>C case, the PSoC chip is configured into the Open Drain, Drives Low mode for the SIO pin. This allows an external pull-up to pull the I<sup>2</sup>C bus voltage above the PSoC pin supply. For example, the PSoC chip could operate at 1.8 V, and an external device could run from 5 V. Note that the SIO pin's  $V_{IH}$  and  $V_{IL}$  levels are determined by the associated  $V_{DDIO}$  supply pin.

The SIO pin must be in one of the following modes: 0 (high impedance analog), 1 (high impedance digital), or 4 (open drain drives low). See [Figure 6-12](#) for details. Absolute maximum ratings for the device must be observed for all I/O pins.

## 6.4.16 Reset Configuration

While reset is active all I/Os are reset to and held in the High Impedance Analog state. After reset is released, the state can be reprogrammed on a port-by-port basis to pull-down or pull-up. To ensure correct reset operation, the port reset configuration data is stored in special nonvolatile registers. The stored reset data is automatically transferred to the port reset configuration registers at reset release.

## 6.4.17 Low-Power Functionality

In all low-power modes the I/O pins retain their state until the part is awakened and changed or reset. To awaken the part, use a pin interrupt, because the port interrupt logic continues to function in all low-power modes.

## 6.4.18 Special Pin Functionality

Some pins on the device include additional special functionality in addition to their GPIO or SIO functionality. The specific special function pins are listed in [Pinouts](#) on page 6. The special features are:

- Digital
  - 4 to 25 MHz crystal oscillator
  - 32.768-kHz crystal oscillator
  - Wake from sleep on I<sup>2</sup>C address match. Any pin can be used for I<sup>2</sup>C if wake from sleep is not required.
  - JTAG interface pins
  - SWD interface pins
  - SWV interface pins
  - External reset
- Analog
  - Opamp inputs and outputs
  - High current IDAC outputs
  - External reference inputs



- Logical OR
- Logical XOR
- Pass, used to pass a value through the ALU to the shift register, mask, or another UDB register

Independent of the ALU operation, these functions are available:

- Shift left
- Shift right
- Nibble swap
- Bitwise OR mask

### 7.2.2.3 Conditionals

Each datapath has two compares, with bit masking options. Compare operands include the two accumulators and the two data registers in a variety of configurations. Other conditions include zero detect, all ones detect, and overflow. These conditions are the primary datapath outputs, a selection of which can be driven out to the UDB routing matrix. Conditional computation can use the built in chaining to neighboring UDBs to operate on wider data widths without the need to use routing resources.

### 7.2.2.4 Variable MSB

The most significant bit of an arithmetic and shift function can be programmatically specified. This supports variable width CRC and PRS functions, and in conjunction with ALU output masking, can implement arbitrary width timers, counters and shift blocks.

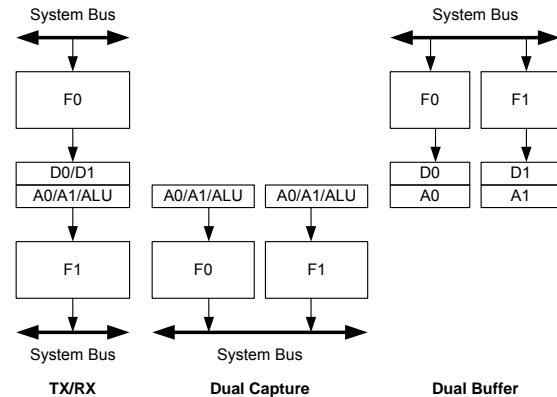
### 7.2.2.5 Built in CRC/PRS

The datapath has built in support for single cycle Cyclic Redundancy Check (CRC) computation and Pseudo Random Sequence (PRS) generation of arbitrary width and arbitrary polynomial. CRC/PRS functions longer than 8 bits may be implemented in conjunction with PLD logic, or built in chaining may be used to extend the function into neighboring UDBs.

### 7.2.2.6 Input/Output FIFOs

Each datapath contains two four-byte deep FIFOs, which can be independently configured as an input buffer (system bus writes to the FIFO, datapath internal reads the FIFO), or an output buffer (datapath internal writes to the FIFO, the system bus reads from the FIFO). The FIFOs generate status that are selectable as datapath outputs and can therefore be driven to the routing, to interact with sequencers, interrupts, or DMA.

**Figure 7-5. Example FIFO Configurations**



### 7.2.2.7 Chaining

The datapath can be configured to chain conditions and signals such as carries and shift data with neighboring datapaths to create higher precision arithmetic, shift, CRC/PRS functions.

### 7.2.2.8 Time Multiplexing

In applications that are over sampled, or do not need high clock rates, the single ALU block in the datapath can be efficiently shared with two sets of registers and condition generators. Carry and shift out data from the ALU are registered and can be selected as inputs in subsequent cycles. This provides support for 16-bit functions in one (8-bit) datapath.

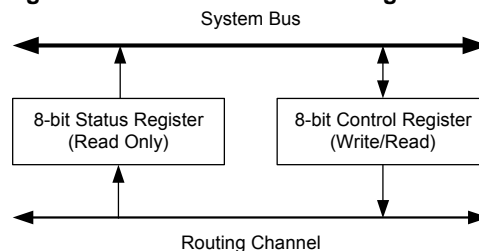
### 7.2.2.9 Datapath I/O

There are six inputs and six outputs that connect the datapath to the routing matrix. Inputs from the routing provide the configuration for the datapath operation to perform in each cycle, and the serial data inputs. Inputs can be routed from other UDB blocks, other device peripherals, device I/O pins, and so on. The outputs to the routing can be selected from the generated conditions, and the serial data outputs. Outputs can be routed to other UDB blocks, device peripherals, interrupt and DMA controller, I/O pins, and so on.

## 7.2.3 Status and Control Module

The primary purpose of this circuitry is to coordinate CPU firmware interaction with internal UDB operation.

**Figure 7-6. Status and Control Registers**



## 7.7 Timers, Counters, and PWMs

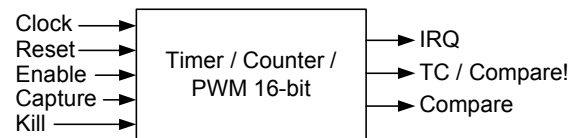
The Timer/Counter/PWM peripheral is a 16-bit dedicated peripheral providing three of the most common embedded peripheral features. As almost all embedded systems use some combination of timers, counters, and PWMs. Four of them have been included on this PSoC device family. Additional and more advanced functionality timers, counters, and PWMs can also be instantiated in Universal Digital Blocks (UDBs) as required. PSoC Creator allows you to choose the timer, counter, and PWM features that they require. The tool set utilizes the most optimal resources available.

The Timer/Counter/PWM peripheral can select from multiple clock sources, with input and output signals connected through the DSI routing. DSI routing allows input and output connections to any device pin and any internal digital signal accessible through the DSI. Each of the four instances has a compare output, terminal count output (optional complementary compare output), and programmable interrupt request line. The Timer/Counter/PWMs are configurable as free running, one shot, or Enable input controlled. The peripheral has timer reset and capture inputs, and a kill input for control of the comparator outputs. The peripheral supports full 16-bit capture.

Timer/Counter/PWM features include:

- 16-bit Timer/Counter/PWM (down count only)
- Selectable clock source
- PWM comparator (configurable for LT, LTE, EQ, GTE, GT)
- Period reload on start, reset, and terminal count
- Interrupt on terminal count, compare true, or capture
- Dynamic counter reads
- Timer capture mode
- Count while enable signal is asserted mode
- Free run mode
- One Shot mode (stop at end of period)
- Complementary PWM outputs with deadband
- PWM output kill

**Figure 7-17. Timer/Counter/PWM**



The PSoC Creator software program provides a user friendly interface to configure the analog connections between the GPIO and various analog resources and connections from one analog resource to another. PSoC Creator also provides component libraries that allow you to configure the various analog blocks to perform application specific functions (PGA, transimpedance amplifier, voltage DAC, current DAC, and so on). The tool also generates API interface libraries that allow you to write firmware that allows the communication between the analog peripheral and CPU/Memory.

### 8.1 Analog Routing

The CY8C34 family of devices has a flexible analog routing architecture that provides the capability to connect GPIOs and different analog blocks, and also route signals between different analog blocks. One of the strong points of this flexible routing architecture is that it allows dynamic routing of input and output connections to the different analog blocks.

For information on how to make pin selections for optimal analog routing, refer to the application note, [AN58304 - PSoC® 3 and PSoC® 5 - Pin Selection for Analog Designs](#).

#### 8.1.1 Features

- Flexible, configurable analog routing architecture
- 16 Analog globals (AG) and two analog mux buses (AMUXBUS) to connect GPIOs and the analog blocks
- Each GPIO is connected to one analog global and one analog mux bus
- 8 Analog local buses (abus) to route signals between the different analog blocks
- Multiplexers and switches for input and output selection of the analog blocks

#### 8.1.2 Functional Description

Analog globals (AGs) and analog mux buses (AMUXBUS) provide analog connectivity between GPIOs and the various analog blocks. There are 16 AGs in the CY8C34 family. The analog routing architecture is divided into four quadrants as shown in [Figure 8-2](#). Each quadrant has four analog globals (AGL[0..3], AGL[4..7], AGR[0..3], AGR[4..7]). Each GPIO is connected to the corresponding AG through an analog switch. The analog mux bus is a shared routing resource that connects to every GPIO through an analog switch. There are two AMUXBUS routes in CY8C34, one in the left half (AMUXBUSL) and one in the right half (AMUXBUSR), as shown in [Figure 8-2](#).

Analog local buses (abus) are routing resources located within the analog subsystem and are used to route signals between different analog blocks. There are eight abus routes in CY8C34, four in the left half (abusl [0:3]) and four in the right half (abusr [0:3]) as shown in Figure 8-2. Using the abus saves the analog globals and analog mux buses from being used for interconnecting the analog blocks.

Multiplexers and switches exist on the various buses to direct signals into and out of the analog blocks. A multiplexer can have only one connection on at a time, whereas a switch can have multiple connections on simultaneously. In Figure 8-2, multiplexers are indicated by grayed ovals and switches are indicated by transparent ovals.

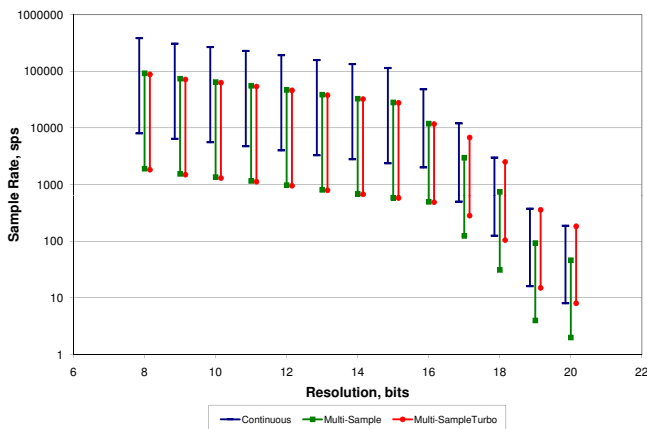
## 8.2 Delta-sigma ADC

The CY8C34 device contains one delta-sigma ADC. This ADC offers differential input, high resolution and excellent linearity, making it a good ADC choice for measurement applications. The converter can be configured to output 12-bit resolution at data rates of up to 192 ksp/s. At a fixed clock rate, resolution can be traded for faster data rates as shown in Table 8-1 and Figure 8-3.

**Table 8-1. Delta-sigma ADC Performance**

Bits	Maximum Sample Rate (sp/s)	SINAD (dB)
12	192 k	66
8	384 k	43

**Figure 8-3. Delta-sigma ADC Sample Rates, Range = ±1.024 V**

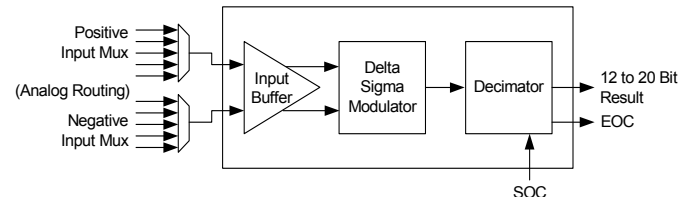


### 8.2.1 Functional Description

The ADC connects and configures three basic components, input buffer, delta-sigma modulator, and decimator. The basic block diagram is shown in Figure 8-4. The signal from the input muxes is delivered to the delta-sigma modulator either directly or through the input buffer. The delta-sigma modulator performs the actual analog to digital conversion. The modulator over-samples the input and generates a serial data stream output. This high speed data stream is not useful for most applications without some type of post processing, and so is passed to the decimator through the Analog Interface block. The decimator converts the

high speed serial data stream into parallel ADC results. The modulator/decimator frequency response is  $[(\sin x)/x]^4$ .

**Figure 8-4. Delta-sigma ADC Block Diagram**



Resolution and sample rate are controlled by the Decimator. Data is pipelined in the decimator; the output is a function of the last four samples. When the input multiplexer is switched, the output data is not valid until after the fourth sample after the switch.

### 8.2.2 Operational Modes

The ADC can be configured by the user to operate in one of four modes: Single Sample, Multi Sample, Continuous, or Multi Sample (Turbo). All four modes are started by either a write to the start bit in a control register or an assertion of the Start of Conversion (SoC) signal. When the conversion is complete, a status bit is set and the output signal End of Conversion (EoC) asserts high and remains high until the value is read by either the DMA controller or the CPU.

#### 8.2.2.1 Single Sample

In Single Sample mode, the ADC performs one sample conversion on a trigger. In this mode, the ADC stays in standby state waiting for the SoC signal to be asserted. When SoC is signaled the ADC performs four successive conversions. The first three conversions prime the decimator. The ADC result is valid and available after the fourth conversion, at which time the EoC signal is generated. To detect the end of conversion, the system may poll a control register for status or configure the external EoC signal to generate an interrupt or invoke a DMA request. When the transfer is done the ADC reenters the standby state where it stays until another SoC event.

#### 8.2.2.2 Continuous

Continuous sample mode is used to take multiple successive samples of a single input signal. Multiplexing multiple inputs should not be done with this mode. There is a latency of three conversion times before the first conversion result is available. This is the time required to prime the decimator. After the first result, successive conversions are available at the selected sample rate.

#### 8.2.2.3 Multi Sample

Multi sample mode is similar to continuous mode except that the ADC is reset between samples. This mode is useful when the input is switched between multiple signals. The decimator is re-primed between each sample so that previous samples do not affect the current conversion. Upon completion of a sample, the next sample is automatically initiated. The results can be transferred using either firmware polling, interrupt, or DMA.

More information on output formats is provided in the Technical Reference Manual.

## 11. Electrical Specifications

Specifications are valid for  $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$  and  $T_J \leq 100\text{ }^{\circ}\text{C}$ , except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted. The unique flexibility of the PSoC UDBs and analog blocks enable many functions to be implemented in PSoC Creator components, see the component data sheets for full AC/DC specifications of individual functions. See the “[Example Peripherals](#)” section on page 43 for further explanation of PSoC Creator components.

### 11.1 Absolute Maximum Ratings

**Table 11-1. Absolute Maximum Ratings DC Specifications<sup>[18]</sup>**

Parameter	Description	Conditions	Min	Typ	Max	Units
$V_{DDA}$	Analog supply voltage relative to $V_{SSA}$		-0.5	–	6	V
$V_{DDD}$	Digital supply voltage relative to $V_{SSD}$		-0.5	–	6	V
$V_{DDIO}$	I/O supply voltage relative to $V_{SSD}$		-0.5	–	6	V
$V_{CCA}$	Direct analog core voltage input		-0.5	–	1.95	V
$V_{CCD}$	Direct digital core voltage input		-0.5	–	1.95	V
$V_{SSA}$	Analog ground voltage		$V_{SSD} - 0.5$	–	$V_{SSD} + 0.5$	V
$V_{GPIO}^{[19]}$	DC input voltage on GPIO	Includes signals sourced by $V_{DDA}$ and routed internal to the pin	$V_{SSD} - 0.5$	–	$V_{DDIO} + 0.5$	V
$V_{SIO}$	DC input voltage on SIO	Output disabled	$V_{SSD} - 0.5$	–	7	V
		Output enabled	$V_{SSD} - 0.5$	–	6	V
$V_{IND}$	Voltage at boost converter input		0.5	–	5.5	V
$V_{BAT}$	Boost converter supply		$V_{SSD} - 0.5$	–	5.5	V
$I_{VDDIO}$	Current per $V_{DDIO}$ supply pin		–	–	100	mA
$I_{GPIO}$	GPIO current		-30	–	41	mA
$I_{SIO}$	SIO current		-49	–	28	mA
$I_{USBIO}$	USBIO current		-56	–	59	mA
$V_{EXTREF}$	ADC external reference inputs	Pins P0[3], P3[2]	–	–	2	V
LU	Latch up current <sup>[20]</sup>		-140	–	140	mA
$ESD_{HBM}$	Electrostatic discharge voltage, Human body model	$V_{SSA}$ tied to $V_{SSD}$	2200	–	–	V
		$V_{SSA}$ not tied to $V_{SSD}$	750	–	–	V
$ESD_{CDM}$	Electrostatic discharge voltage, Charge device model		500	–	–	V

#### Notes

18. Usage above the absolute maximum conditions listed in [Table 11-1](#) may cause permanent damage to the device. Exposure to Absolute Maximum conditions for extended periods of time may affect device reliability. The Maximum Storage Temperature is 150 °C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When used below Absolute Maximum conditions but above normal operating conditions, the device may not operate to specification.

19. The  $V_{DDIO}$  supply voltage must be greater than the maximum voltage on the associated GPIO pins. Maximum voltage on GPIO pin  $\leq V_{DDIO} \leq V_{DDA}$ .

20. Meets or exceeds JEDEC Spec EIA/JESD78 IC Latch-up Test.

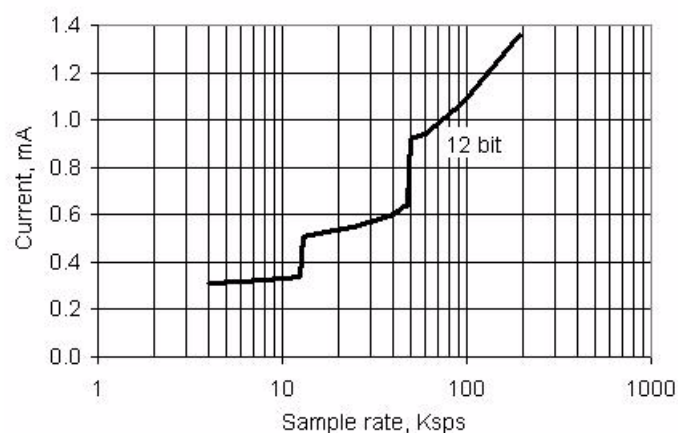
**Table 11-22. Delta-sigma ADC AC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
	Startup time		–	–	4	Samples
THD	Total harmonic distortion <sup>[51]</sup>	Buffer gain = 1, 12-bit, Range = $\pm 1.024$ V	–	–	0.0032	%
<b>12-Bit Resolution Mode</b>						
SR12	Sample rate, continuous, high power <sup>[51]</sup>	Range = $\pm 1.024$ V, unbuffered	4	–	192	ksps
BW12	Input bandwidth at max sample rate <sup>[51]</sup>	Range = $\pm 1.024$ V, unbuffered	–	44	–	kHz
SINAD12int	Signal to noise ratio, 12-bit, internal reference <sup>[51]</sup>	Range = $\pm 1.024$ V, unbuffered	66	–	–	dB
<b>8-Bit Resolution Mode</b>						
SR8	Sample rate, continuous, high power <sup>[51]</sup>	Range = $\pm 1.024$ V, unbuffered	8	–	384	ksps
BW8	Input bandwidth at max sample rate <sup>[51]</sup>	Range = $\pm 1.024$ V, unbuffered	–	88	–	kHz
SINAD8int	Signal to noise ratio, 8-bit, internal reference <sup>[51]</sup>	Range = $\pm 1.024$ V, unbuffered	43	–	–	dB

**Table 11-23. Delta-sigma ADC Sample Rates, Range =  $\pm 1.024$  V**

Resolution, Bits	Continuous		Multi-Sample	
	Min	Max	Min	Max
8	8000	384000	1911	91701
9	6400	307200	1543	74024
10	5566	267130	1348	64673
11	4741	227555	1154	55351
12	4000	192000	978	46900

**Figure 11-33. Delta-sigma ADC IDD vs sps, Range =  $\pm 1.024$  V, Continuous Sample Mode, Input Buffer Bypassed**



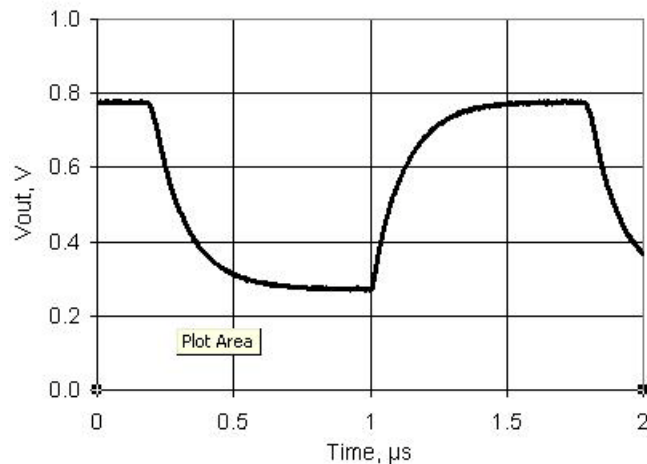
**Note**

51. Based on device characterization (Not production tested).

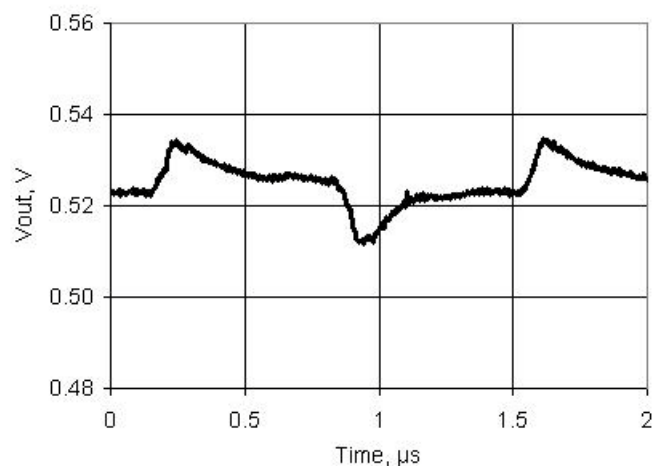
**Table 11-31. VDAC AC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
F <sub>DAC</sub>	Update rate	1 V scale	–	–	1000	ksps
		4 V scale	–	–	250	ksps
T <sub>settleP</sub>	Settling time to 0.1%, step 25% to 75%	1 V scale, Cload = 15 pF	–	0.45	1	μs
		4 V scale, Cload = 15 pF	–	0.8	3.2	μs
T <sub>settleN</sub>	Settling time to 0.1%, step 75% to 25%	1 V scale, Cload = 15 pF	–	0.45	1	μs
		4 V scale, Cload = 15 pF	–	0.7	3	μs
	Voltage noise	Range = 1 V, High speed mode, V <sub>DDA</sub> = 5 V, 10 kHz	–	750	–	nV/sqrtHz

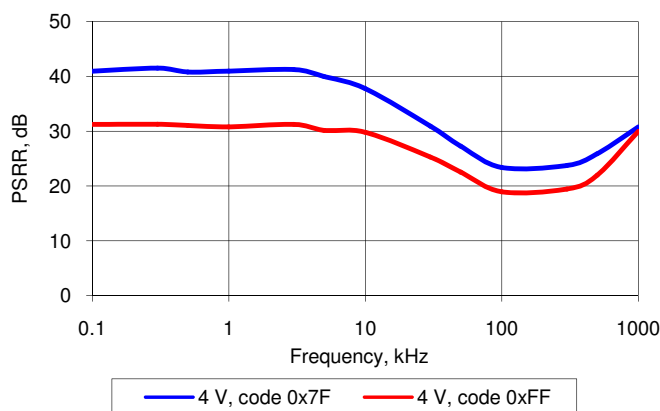
**Figure 11-56. VDAC Step Response, Codes 0x40 - 0xC0, 1 V Mode, High speed mode, V<sub>DDA</sub> = 5 V**



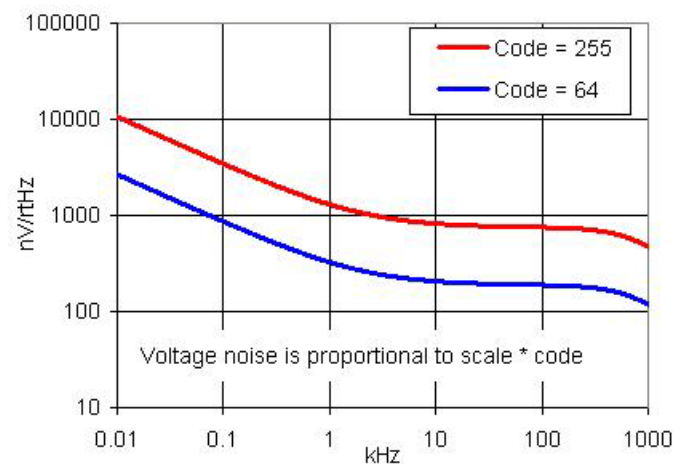
**Figure 11-57. VDAC Glitch Response, Codes 0x7F - 0x80, 1 V Mode, High speed mode, V<sub>DDA</sub> = 5 V**



**Figure 11-58. VDAC PSRR vs Frequency**



**Figure 11-59. VDAC Voltage Noise, 1 V Mode, High speed mode, V<sub>DDA</sub> = 5 V**





## 11.9 Clocking

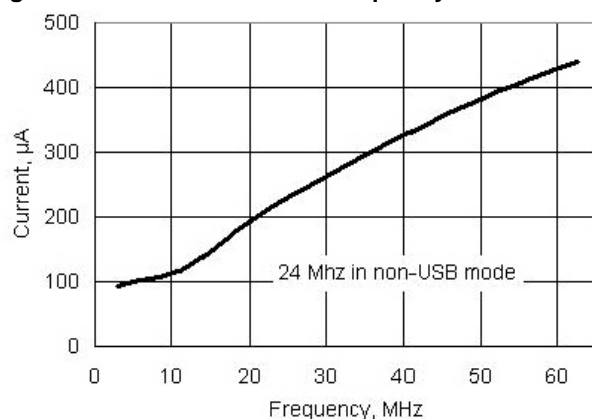
Specifications are valid for  $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$  and  $T_J \leq 100\text{ }^{\circ}\text{C}$ , except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

### 11.9.1 Internal Main Oscillator

**Table 11-73. IMO DC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
	Supply current					
	24 MHz – USB mode	With oscillator locking to USB bus	–	–	500	μA
	24 MHz – non USB mode		–	–	300	μA
	12 MHz		–	–	200	μA
	6 MHz		–	–	180	μA
	3 MHz		–	–	150	μA

**Figure 11-70. IMO Current vs. Frequency**



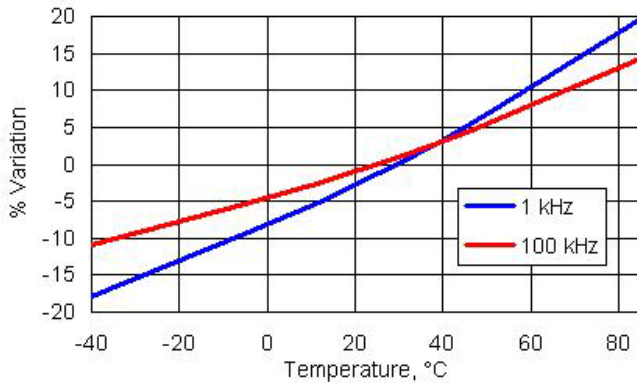
**Table 11-74. IMO AC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
F <sub>IMO</sub>	IMO frequency stability (with factory trim)					
	24 MHz – Non USB mode		–4	–	4	%
	24 MHz – USB mode	With oscillator locking to USB bus	–0.25	–	0.25	%
	12 MHz		–3	–	3	%
	6 MHz		–2	–	2	%
	3 MHz		–2	–	2	%
	Startup time <sup>[73]</sup>	From enable (during normal system operation)	–	–	13	μs
J <sub>p-p</sub>	Jitter (peak to peak) <sup>[73]</sup>					
	F = 24 MHz		–	0.9	–	ns
	F = 3 MHz		–	1.6	–	ns
J <sub>period</sub>	Jitter (long term) <sup>[73]</sup>					
	F = 24 MHz		–	0.9	–	ns
	F = 3 MHz		–	12	–	ns

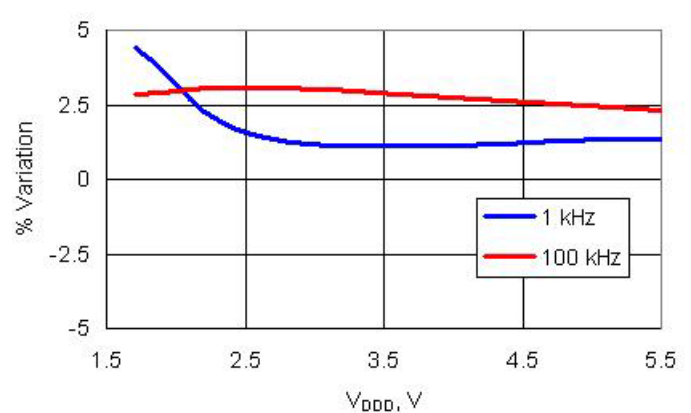
**Note**

<sup>73</sup>. Based on device characterization (Not production tested).

**Figure 11-73. ILO Frequency Variation vs. Temperature**



**Figure 11-74. ILO Frequency Variation vs. V<sub>DD</sub>**



### 11.9.3 MHz External Crystal Oscillator

For more information on crystal or ceramic resonator selection for the MHzECO, refer to application note [AN54439: PSoC 3 and PSoC 5 External Oscillators](#).

**Table 11-77. MHzECO DC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
I <sub>CC</sub>	Operating current <sup>[75]</sup>	13.56 MHz crystal	–	3.8	–	mA

**Table 11-78. MHzECO AC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
F	Crystal frequency range		4	–	25	MHz

### 11.9.4 kHz External Crystal Oscillator

**Table 11-79. kHzECO DC Specifications<sup>[75]</sup>**

Parameter	Description	Conditions	Min	Typ	Max	Units
I <sub>CC</sub>	Operating current	Low-power mode; CL = 6 pF	–	0.25	1.0	μA
DL	Drive level		–	–	1	μW

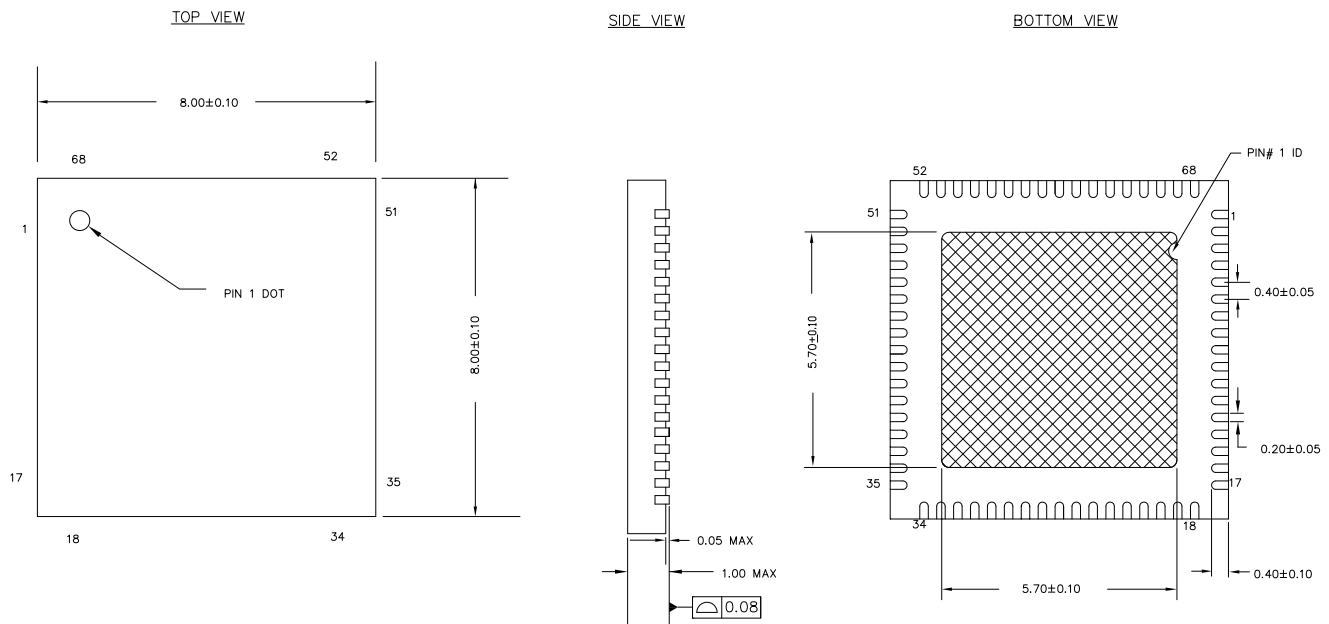
**Table 11-80. kHzECO AC Specifications**

Parameter	Description	Conditions	Min	Typ	Max	Units
F	Frequency		–	32.768	–	kHz
T <sub>ON</sub>	Startup time	High-power mode	–	1	–	s


**Note**

75. Based on device characterization (Not production tested).

**Figure 13-3. 68-pin QFN 8 × 8 with 0.4 mm Pitch Package Outline (Sawn Version)**

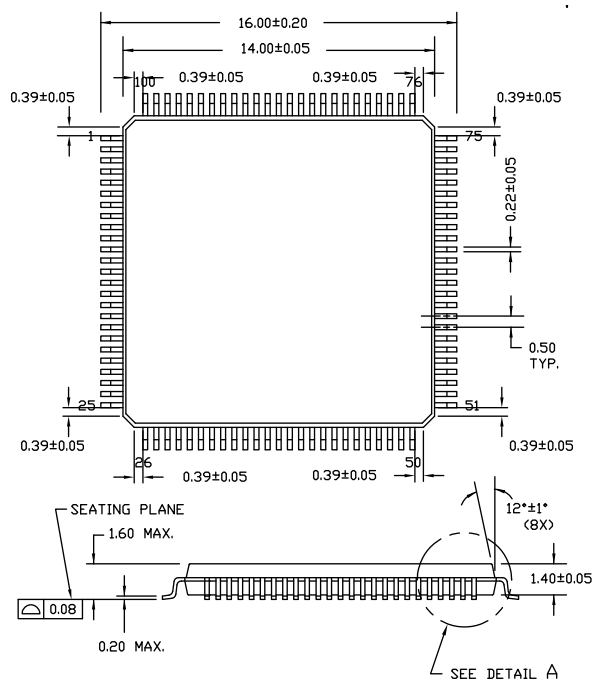


**NOTES:**

1.  HATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MO-220
3. PACKAGE WEIGHT: 17 ± 2mg
4. ALL DIMENSIONS ARE IN MILLIMETERS

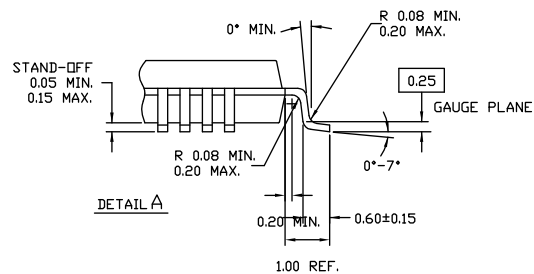
001-09618 \*E

**Figure 13-4. 100-pin TQFP (14 × 14 × 1.4 mm) Package Outline**

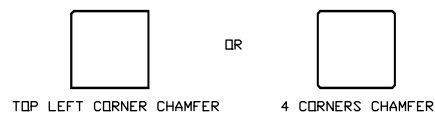


**NOTE:**

1. JEDEC STD REF MS-026
2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH  
MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.0098 in (0.25 mm) PER SIDE  
BODY LENGTH DIMENSIONS ARE MAX PLASTIC BODY SIZE INCLUDING MOLD MISMATCH
3. DIMENSIONS IN MILLIMETERS



**NOTE:** PKG. CAN HAVE



51-85048 \*J

## 17. Revision History

Description Title: PSoC® 3: CY8C34 Family Datasheet Programmable System-on-Chip (PSoC®) Document Number: 001-53304				
Revision	ECN	Submission Date	Orig. of Change	Description of Change
**	2714270	06/03/09	VVSK	New data sheet
*A	2758970	09/02/09	MKEA	Updated Part Numbering Conventions Added Section 11.7.5 (EMIF Figures and Tables) Updated GPIO and SIO AC specifications Updated XRES Pin Description and Xdata Address Map specifications Updated DFB and Comparator specifications Updated PHUB features section and RTC in sleep mode Updated IDAC and VDAC DC and Analog Global specifications Updated USBIO AC and Delta Sigma ADC specifications Updated PPOR and Voltage Monitors DC specifications Updated Drive Mode diagram Added 48-QFN Information Updated other electrical specifications
*B	2824546	12/09/09	MKEA	Updated I2C section to reflect 1 Mbps. Updated Table 11-6 and 11-7 (Boost AC and DC specs); also added Schottky Diode specs. Changed current for sleep/hibernate mode to include SIO; Added footnote to analog global specs. Updated Figures 1-1, 6-2, 7-14, and 8-1. Updated Table 6-2 and Table 6-3 (Hibernate and Sleep rows) and Power Modes section. Updated GPIO and SIO AC specifications. Updated Gain error in IDAC and VDAC specifications. Updated description of $V_{DDA}$ spec in Table 11-1 and removed GPIO Clamp Current parameter. Updated number of UDBs on page 1. Moved FILO from ILO DC to AC table. Added PCB Layout and PCB Schematic diagrams. Updated Fgpioout spec (Table 11-9). Added duty cycle frequency in PLL AC spec table. Added note for Sleep and Hibernate modes and Active Mode specs in Table 11-2. Linked URL in Section 10.3 to PSoC Creator site. Updated Ja and Jc values in Table 13-1. Updated Single Sample Mode and Fast FIR Mode sections. Updated Input Resistance specification in Del-Sig ADC table. Added Tio_init parameter. Updated PGA and UGB AC Specs. Removed SPC ADC. Updated Boost Converter section. Added section 'SIO as Comparator'; updated Hysteresis spec (differential mode) in Table 11-10. Updated $V_{BAT}$ condition and deleted Vstart parameter in Table 11-6. Added 'Bytes' column for Tables 4-1 to 4-5.
*C	2873322	02/04/10	MKEA	Changed maximum value of PPOR_TR to '1'. Updated Vbias specification. Updated PCB Schematic. Updated Figure 8-1 and Figure 6-3. Updated Interrupt Vector table, Updated Sales links. Updated JTAG and SWD specifications. Removed Jp-p and Jperiod from ECO AC Spec table. Added note on sleep timer in Table 11-2. Updated ILO AC and DC specifications. Added Resolution parameter in VDAC and IDAC tables. Updated $I_{OUT}$ typical and maximum values. Changed Temperature Sensor range to -40 °C to +85 °C. Removed Latchup specification from Table 11-1.

**Description Title: PSoC® 3: CY8C34 Family Datasheet Programmable System-on-Chip (PSoC®) (continued)**  
**Document Number: 001-53304**

Revision	ECN	Submission Date	Orig. of Change	Description of Change
*D	2903576	04/01/10	MKEA	<p>Updated Vb pin in PCB Schematic</p> <p>Updated Tstartup parameter in AC Specifications table</p> <p>Added Load regulation and Line regulation parameters to Inductive Boost Regulator DC Specifications table</p> <p>Updated I<sub>CC</sub> parameter in LCD Direct Drive DC Specs table</p> <p>In page 1, updated internal oscillator range under Precision programmable clocking to start from 3 MHz</p> <p>Updated I<sub>OUT</sub> parameter in LCD Direct Drive DC Specs table</p> <p>Updated Table 6-2 and Table 6-3</p> <p>Removed DFB block in Figure 1-1.</p> <p>Added bullets on CapSense in page 1; added CapSense column in Section 12</p> <p>Removed some references to footnote [1]</p> <p>Changed INC_Rn cycles from 3 to 2 (Table 4-1)</p> <p>Added footnote in PLL AC Specification table</p> <p>Added PLL intermediate frequency row with footnote in PLL AC Specs table</p> <p>Added UDBs subsection under 11.6 Digital Peripherals</p> <p>Updated Figure 2-6 (PCB Layout)</p> <p>Updated Pin Descriptions section and modified Figures 6-6, 6-8, 6-9</p> <p>Updated LVD in Tables 6-2 and 6-3; modified Low-power modes bullet in page 1</p> <p>Added note to Figures 2-5 and 6-2; Updated Figure 6-2 to add capacitors for V<sub>DDA</sub> and V<sub>DDD</sub> pins.</p> <p>Updated boost converter section (6.2.2)</p> <p>Updated Tstartup values in Table 11-3.</p> <p>Removed IPOR rows from Table 11-67.</p> <p>Updated 6.3.1.1, Power Voltage Level Monitors.</p> <p>Updated section 5.2 and Table 11-2 to correct suggestion of execution from flash.</p> <p>Updated IMO max frequency in Figure 6-1, Table 11-77, and Table 11-78.</p> <p>Updated V<sub>REF</sub> specs in Table 11-21.</p> <p>Updated IDAC uncompensated gain error in Table 11-25.</p> <p>Updated Delay from Interrupt signal input to ISR code execution from ISR code in Table 11-57. Removed other line in table.</p> <p>Added sentence to last paragraph of section 6.1.1.3.</p> <p>Updated T<sub>RESP</sub>, high and low-power modes, in Table 11-24.</p> <p>Updated f<sub>TCK</sub> values in Table 11-72 and f<sub>SWDCK</sub> values in Table 11-73.</p> <p>Updated SNR condition in Table 11-20.</p> <p>Updated sleep wakeup time in Table 6-3 and Tsleep in Table 11-3.</p> <p>Added 1.71 V ≤ V<sub>DDD</sub> &lt; 3.3 V, SWD over USBIO pins value to Table 11-73.</p> <p>Removed mention of hibernate reset (HRES) from page 1 features, Table 6-3, Section 6.2.1.4, Section 6.3, and Section 6.3.1.1. Change PPOR/PRES to TBDs in Section 6.3.1.1, Section 6.4.1.6 (changed PPOR to reset), Table 11-3 (changed PPOR to PRES), Table 11-67 (changed title, values TBD), and Table 11-68 (changed PPOR_TR to PRES_TR).</p> <p>Added sentence saying that LVD circuits can generate a reset to Section 6.3.1.1.</p> <p>Changed I<sub>DD</sub> values on page 1, page 5, and Table 11-2.</p> <p>Changed resume time value in Section 6.2.1.3.</p> <p>Changed ESD HBM value in Table 11-1.</p> <p>Changed sample rate row in Table 11-20. Removed V<sub>DDA</sub> = 1.65 V rows and changed BWag value in Table 11-22.</p> <p>Changed V<sub>IOFF</sub> values and changed CMRR value in Table 11-23.</p> <p>Changed INL max value in Table 11-27.</p> <p>Added max value to the Quiescent current specs in Tables 11-29 and 11-31.</p> <p>Changed occurrences of “Block” to “Row” and deleted the “ECC not included” footnote in Table 11-55.</p> <p>Changed max response time value in Tables 11-68 and 11-70.</p> <p>Changed the Startup time in Table 11-78.</p> <p>Added condition to intermediate frequency row in Table 11-84.</p> <p>Added row to Table 11-68.</p> <p>Added brown out note to Section 11.8.1.</p>

**Description Title: PSoC® 3: CY8C34 Family Datasheet Programmable System-on-Chip (PSoC®) (continued)**  
**Document Number: 001-53304**

Revision	ECN	Submission Date	Orig. of Change	Description of Change
*M	3464258	12/14/2011	MKEA	<p>Updated Analog Global specs</p> <p>Updated IDAC range</p> <p>Updated TIA section</p> <p>Modified VDDIO description in Section 3</p> <p>Added note on Sleep and Hibernate modes in the Power Modes section</p> <p>Updated Boost Converter section</p> <p>Updated conditions for Inductive boost AC specs</p> <p>Added VDAC/IDAC noise graphs and specs</p> <p>Added pin capacitance specs for ECO pins</p> <p>Removed <math>C_L</math> from 32 kHz External Crystal DC Specs table.</p> <p>Added reference to AN54439 in Section 6.1.2.2</p> <p>Deleted T_SWDO_hold row from the SWD Interface AC Specifications table</p> <p>Removed Pin 46 connections in "Example Schematic for 100-pin TQFP Part with Power Connections"</p> <p>Updated Active Mode IDD description in Table 11-2.</p> <p>Added <math>I_{DDDR}</math> and <math>I_{DDAR}</math> specs in Table 11-2.</p> <p>Replaced "total device program time" with <math>T_{PROG}</math> in Flash AC specs table</p> <p>Added <math>I_{GPIO}</math>, <math>I_{SIO}</math> and <math>I_{USBIO}</math> specs in Absolute Maximum Ratings</p> <p>Added conditions to <math>I_{CC}</math> spec in 32 kHz External Crystal DC Specs table.</p> <p>Updated <math>TCV_{OS}</math> value</p> <p>Removed Boost Efficiency vs <math>V_{OUT}</math> graph</p> <p>Updated boost graphs</p> <p>Updated min value of GPIO input edge rate</p> <p>Removed 3.4 Mbps in UDBs from I2C section</p> <p>Updated USBIO Block diagram; added USBIO drive mode description</p> <p>Updated Analog Interconnect diagram</p> <p>Changed max IMO startup time to 12 <math>\mu s</math></p> <p>Added note for <math>I_{IL}</math> spec in USBIO DC specs table</p> <p>Updated GPIO Block diagram</p> <p>Updated voltage reference specs</p> <p>Added text explaining power supply ramp up in Section 11-4.</p>